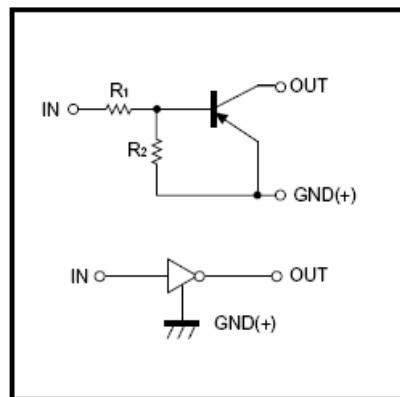


## FEATURES

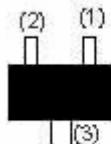
- \* Built-in bias resistors enable the configuration of an inverter circuit without connecting input resistors (see equivalent circuit).
- \* Only the on/off conditions need to be set for operation, making device design easy.
- \* The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.

### ●Equivalent circuit



## PIN CONNECTIONS AND MARKING

DTA123JE

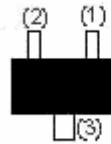


1.IN  
2.GND  
3.OUT

SOT-523

Abbreviated symbol: E32

DTA123JUA

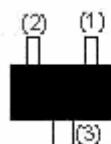


1.IN  
2.GND  
3.OUT

SOT-323

Abbreviated symbol: 132

DTA123JKA

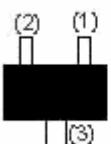


1.IN  
2.GND  
3.OUT

SOT-23-3L

Abbreviated symbol: E32

DTA123JCA

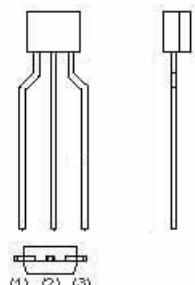


1.IN  
2.GND  
3.OUT

SOT-23

Abbreviated symbol: E32

DTA123JSA



1.GND  
2.OUT  
3.IN

TO-92S

**Absolute maximum ratings(Ta=25°C)**

Parameter	Symbol	Limits (DTA123J□ )					Unit
		E	UA	KA	CA	SA	
Supply voltage	V <sub>CC</sub>			-50			V
Input voltage	V <sub>IN</sub>			-12~+5			V
Output current	I <sub>O</sub>			-100			mA
	I <sub>C(MAX)</sub>			-100			
Power dissipation	P <sub>d</sub>	150		200		300	mW
Junction temperature	T <sub>j</sub>			150			°C
Storage temperature	T <sub>stg</sub>			-55~150			°C

**Electrical characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>			-0.5	V	V <sub>CC</sub> =-5V, I <sub>O</sub> =-100μA
	V <sub>I(on)</sub>	-1.1				V <sub>O</sub> =-0.3V, I <sub>O</sub> =-5mA
Output voltage	V <sub>O(on)</sub>		-0.1	-0.3	V	I <sub>O</sub> /I <sub>I</sub> =-5mA/-0.25mA
Input current	I <sub>I</sub>			-3.6	mA	V <sub>I</sub> =-5V
Output current	I <sub>O(off)</sub>			-0.5	μA	V <sub>CC</sub> =-50V, V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	80				V <sub>O</sub> =-5V, I <sub>O</sub> =-10mA
Input resistance	R <sub>I</sub>	1.54	2.2	2.86	KΩ	-
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	17	21	26		-
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>O</sub> =-10V, I <sub>O</sub> =-5mA, f=100MHz

**Typical Characteristics**

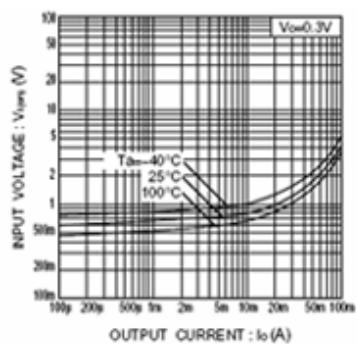


Fig.1 Input voltage vs. output current  
(ON characteristics)

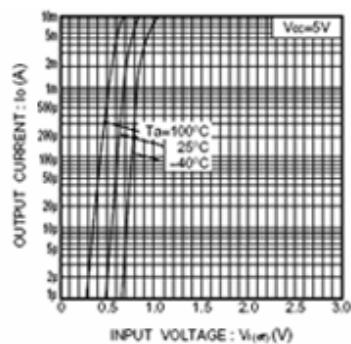


Fig.2 Output current vs. input voltage  
(OFF characteristics)

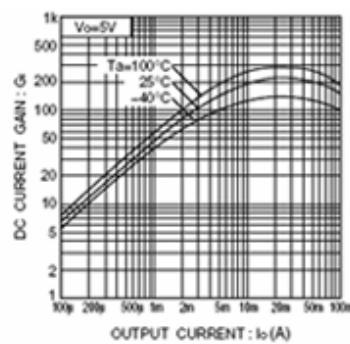


Fig.3 DC current gain vs. output current

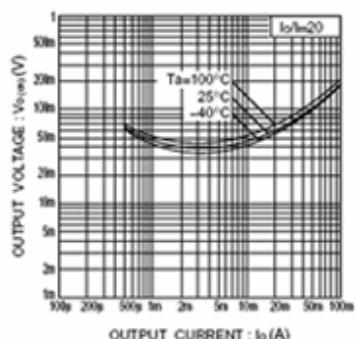


Fig.4 Output voltage vs. output current